

Peak Emission Wavelength: 870nm

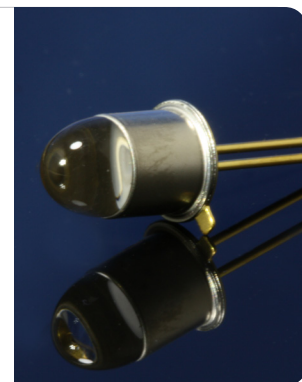
The 870nm high power infrared LED Series is designed for application requiring high accuracy and precision as well as uniform spectral emission. Custom package solutions and sorting are available.

FEATURES

- > Hermetically Sealed TO-18
- > High Output Power
- > High Reliability in Demanding Environments
- > Narrow Beam Angle / High Reliability

APPLICATIONS

- > Optical Scanning
- > Linear & Rotary Encoder
- > Edge Sensing / Optical Sensors
- > Optical Switches / Security Systems



Absolute Maximum Ratings (Ta=25°C)



ITEMS	SYMBOL	RATINGS	UNIT
Forward Current (DC)	IF	100	mA
Forward Current (Pulse)*1	IFP	1	A
Reverse Voltage	VR	5	V
Power Dissipation	PD	180	mW
Operating Temperature Range	Topr	-20 ~ +85	°C
Storage Temperature Range	Tstg	-30 ~ +100	°C
Junction Temperature	Tj	100	°C
Lead Soldering Temperature	Tls	320	°C

*1: Tw=10μsec, T=10mS *2: Time 2 Sec max, Position: Up to 3mm from the body.

Electrical & Optical Characteristics (Ta = 25°C)

ITEMS	SYMBOL	CONDITIONS	MIN	TYP	MAX	UNIT
Power Output	PO	IF=50mA	--	20	--	mW
Forward Voltage	VF	IF=50mA	--	1.45	--	V
Reverse Current	IR	VR=5V	--	--	10	μA
Peak Emission Wavelength	λp	IF=50mA	--	870	--	nm
Spectral Line Half Width	Δλ	IF=50mA	--	45	--	nm
Half Intensity Beam Angle	Θ	IF=50mA	--	±5	--	deg

